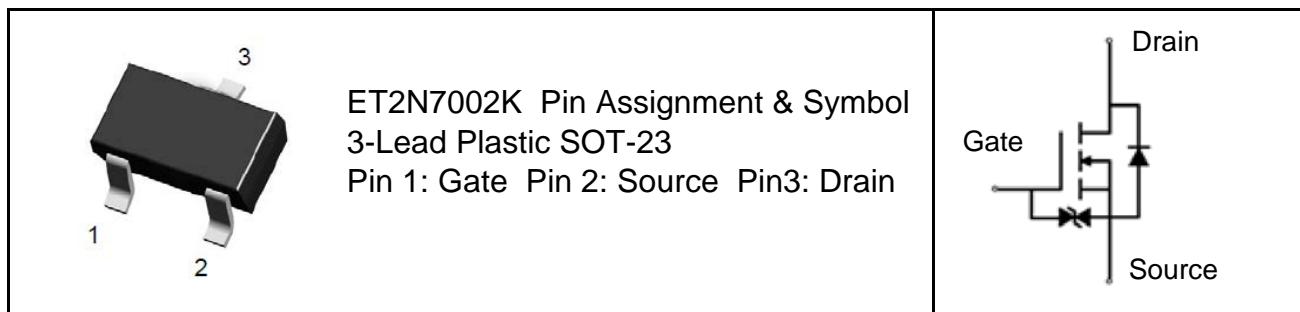


**N-Channel High Density Trench MOSFET (60V,0.5A)****PRODUCT SUMMARY**

V_{DSS}	I_D	$R_{DS(on)}$ (mΩ) Typ
60V	500mA	2.5 @ $V_{GS} = 10V$, $I_D = 0.5A$
		3.0 @ $V_{GS} = 5V$, $I_D = 0.05A$

Features

- High speed switch
- Advanced Trench Process Technology
- SOT-23 package
- ESD protected up to 2KV
- Lead (Pb) -free and halogen-free

**Absolute Maximum Ratings** ($T_A=25^\circ C$, unless otherwise noted)

Symbol	Parameter	Ratings	Units
V_{DS}	Drain-Source Voltage	60	V
V_{GS}	Gate-Source Voltage	± 15	V
I_D	Drain Current (Continuous)	0.2	A
I_{DM}	Drain Current (Pulsed) ^a	0.8	A
P_D	Total Power Dissipation @ $T_A=25^\circ C$	0.3	W
I_S	Maximum Diode Forward Current	0.5	A
T_j, T_{stg}	Operating Junction and Storage Temperature Range	-55 to +150	°C
R_{QJA}	Thermal Resistance Junction to Ambient (PCB mounted) ^b	357	°C/W

a: Repetitive Rating: Pulse width limited by the maximum junction temperature.

b: 1-in² 2oz Cu PCB board



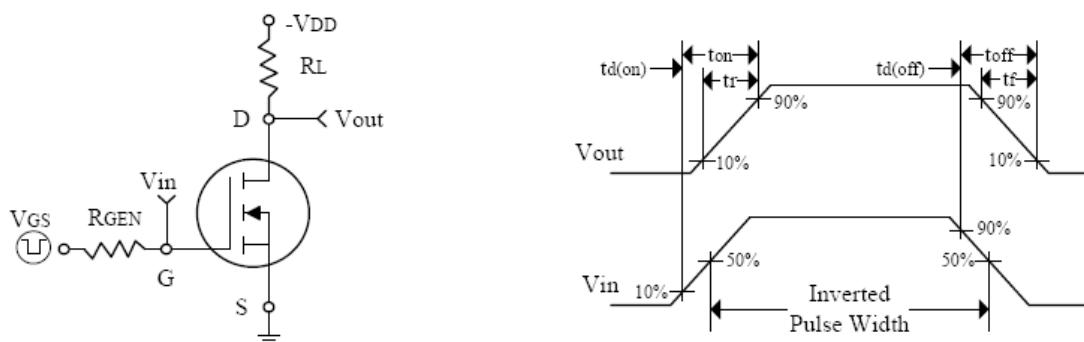
Eternal Semiconductor Inc.

ET2N7002K

Electrical Characteristics ($T_A=25^\circ\text{C}$, unless otherwise noted)

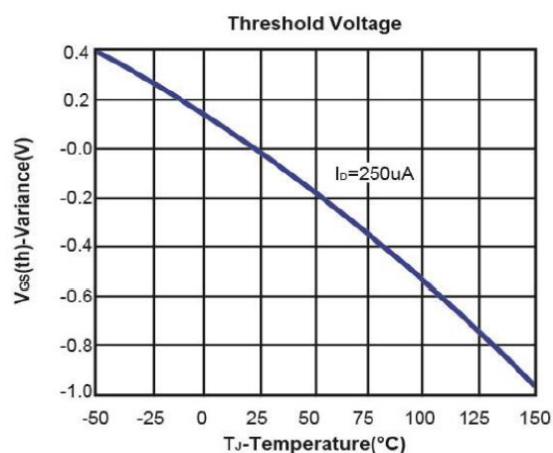
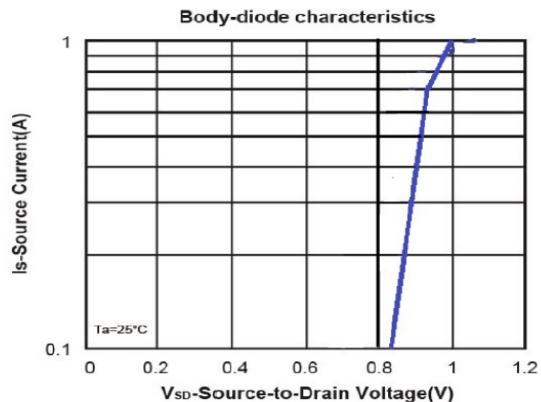
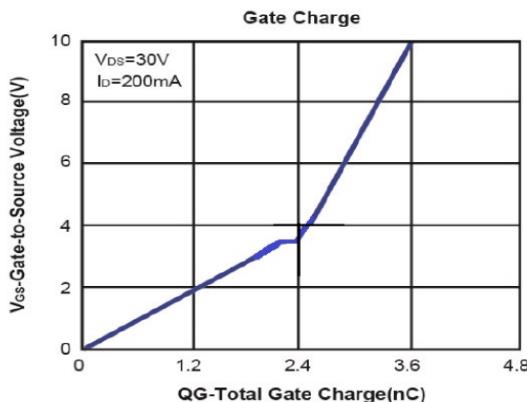
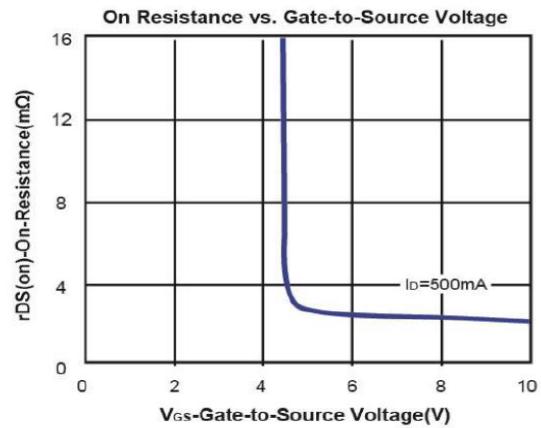
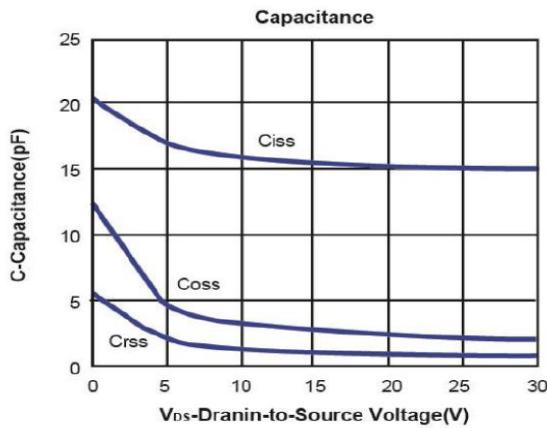
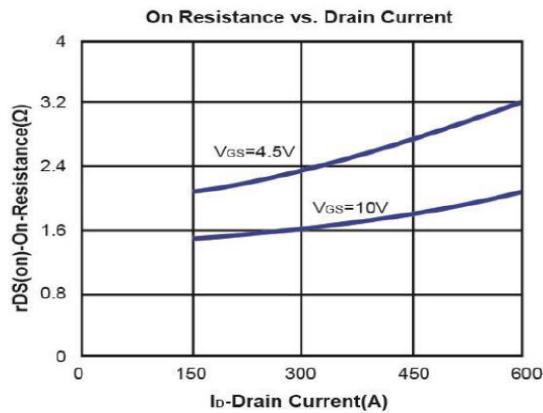
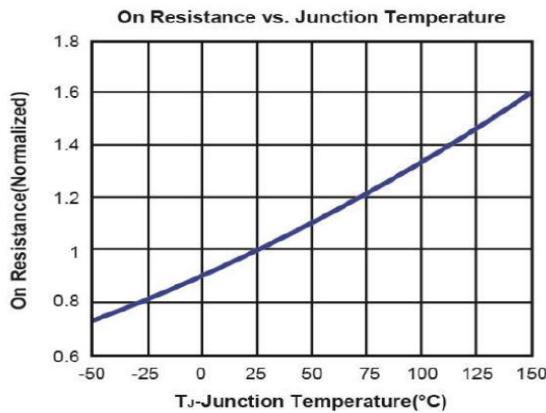
Symbol	Characteristic	Test Conditions	Min.	Typ.	Max.	Unit
• Off Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{\text{GS}}=0\text{V}$, $I_D=10\mu\text{A}$	60	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{\text{DS}}=60\text{V}$, $V_{\text{GS}}=0\text{V}$	-	-	1	μA
I_{GSS}	Gate-Body Leakage Current	$V_{\text{GS}}=\pm 15\text{V}$, $V_{\text{DS}}=0\text{V}$	-	-	± 1	μA
• On Characteristics						
$V_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$V_{\text{DS}}=V_{\text{GS}}$, $I_D=250\mu\text{A}$	1.35	-	0	V
$R_{\text{DS}(\text{on})}$	Drain-Source On-State Resistance	$V_{\text{GS}}=10\text{V}$, $I_D=0.5\text{A}$	-	2.5	4.0	Ω
		$V_{\text{GS}}=5\text{V}$, $I_D=0.05\text{A}$	-	3.0	4.0	
• Dynamic Characteristics						
C_{iss}	Input Capacitance	$V_{\text{DS}}=25\text{V}$, $V_{\text{GS}}=0\text{V}$, $f=1\text{MHz}$	-	-	60	PF
C_{oss}	Output Capacitance		-	-	30	
C_{rss}	Reverse Transfer Capacitance		-	-	10	
• Switching Characteristics						
$t_{\text{d}(\text{on})}$	Turn-on Delay Time	$V_{\text{DD}}=15\text{V}$, $R_L=23\Omega$, $I_D=0.5\text{A}$, $\text{VGEN}=10\text{V}$, $\text{RG}=25\Omega$	-	-	15	nS
$t_{\text{d}(\text{off})}$	Turn-off Delay Time		-	-	15	
• Drain-Source Diode Characteristics						
V_{SD}	Drain-Source Diode Forward	$V_{\text{GS}}=0\text{V}$, $I_S=0.2\text{A}$	-	-	2.5	V

Note: Pulse Test: Pulse Width $\leq 300\text{us}$, Duty Cycle $\leq 2\%$



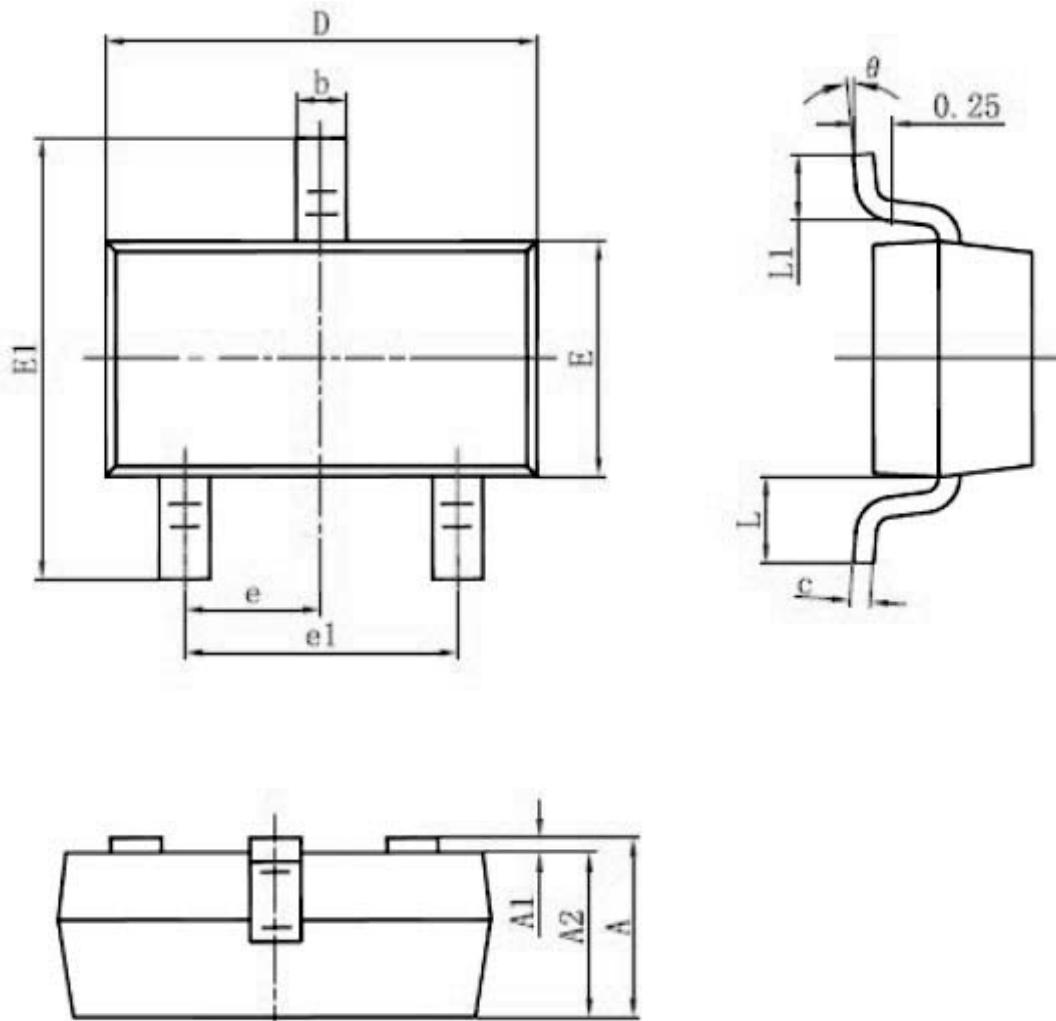
Switching Test Circuit and Switching Waveforms

Typical Characteristics Curves (Ta=25°C, unless otherwise note)





SOT-23 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

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